

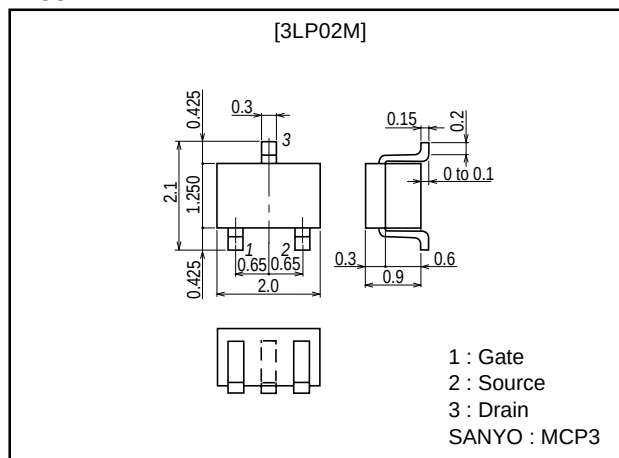
SANYO**Ultrahigh-Speed Switching Applications****Features**

- Low ON resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit:mm

2158

**Specifications****Absolute Maximum Ratings** at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DS}		-30	V
Gate-to-Source Voltage	V_{GS}		± 10	V
Drain Current (DC)	I_D		-0.2	A
Drain Current (pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-0.8	A
Allowable Power Dissipation	P_D		0.15	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}$, $V_{GS} = 0$	-30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -30\text{V}$, $V_{GS} = 0$			-10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 8\text{V}$, $V_{DS} = 0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{V}$, $I_D = -100\mu\text{A}$	-0.4		-1.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10\text{V}$, $I_D = -100\text{mA}$	0.21	0.3		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -100\text{mA}$, $V_{GS} = -4\text{V}$		2.4	3.1	Ω
	$R_{DS(on)2}$	$I_D = -50\text{mA}$, $V_{GS} = -2.5\text{V}$		3.5	4.9	Ω
	$R_{DS(on)3}$	$I_D = -10\text{mA}$, $V_{GS} = -1.5\text{V}$		10	20	Ω

Marking : XD

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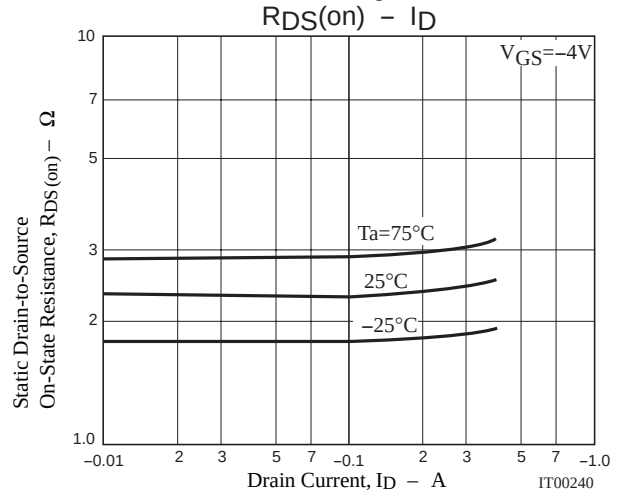
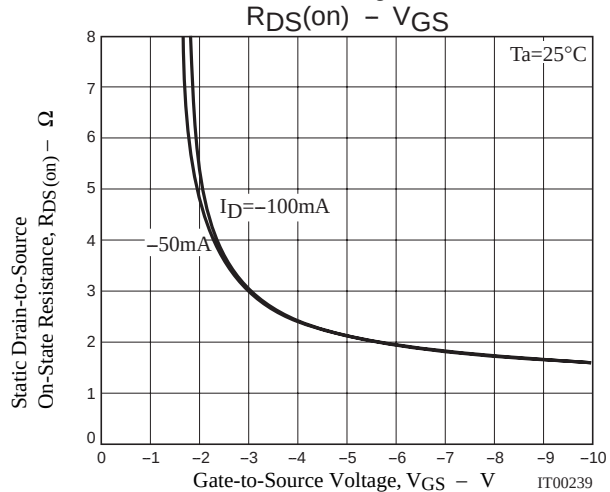
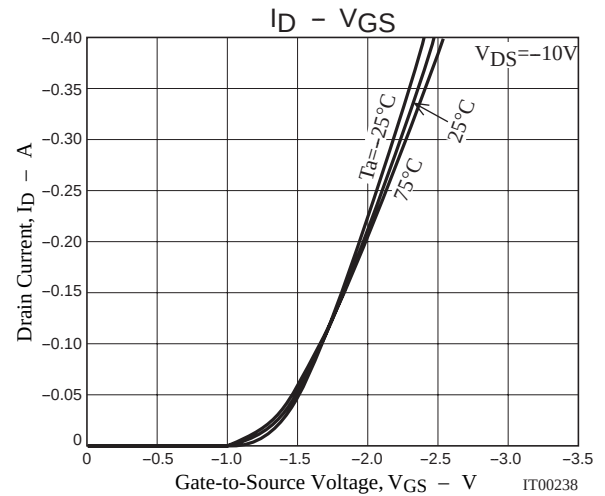
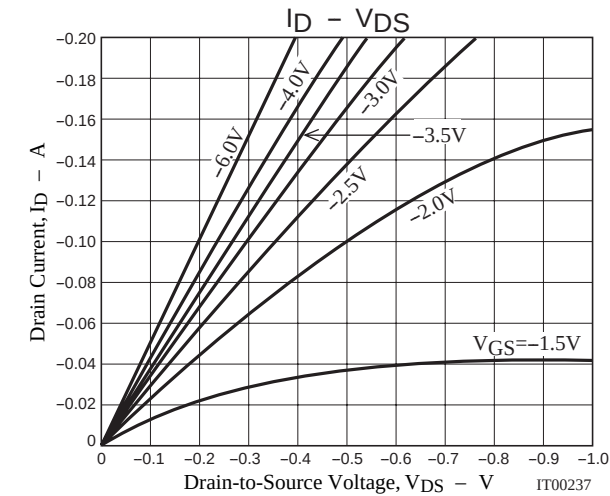
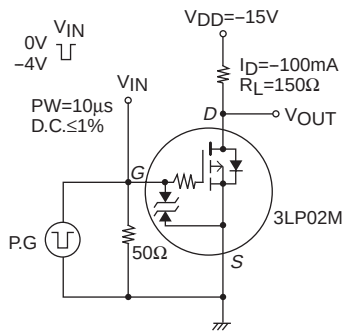
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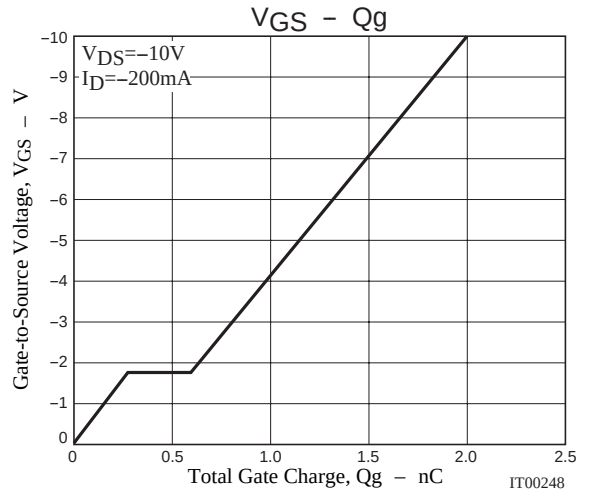
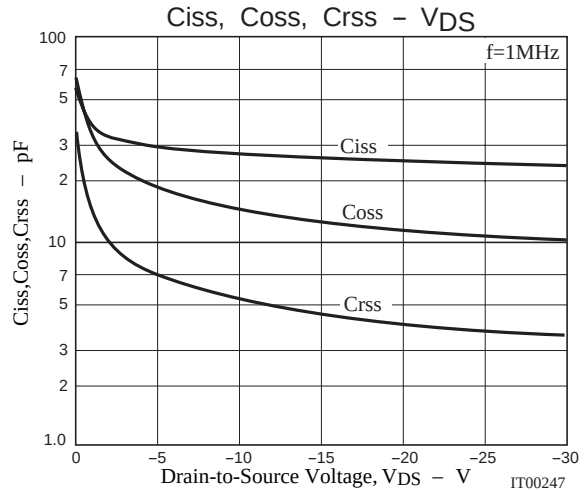
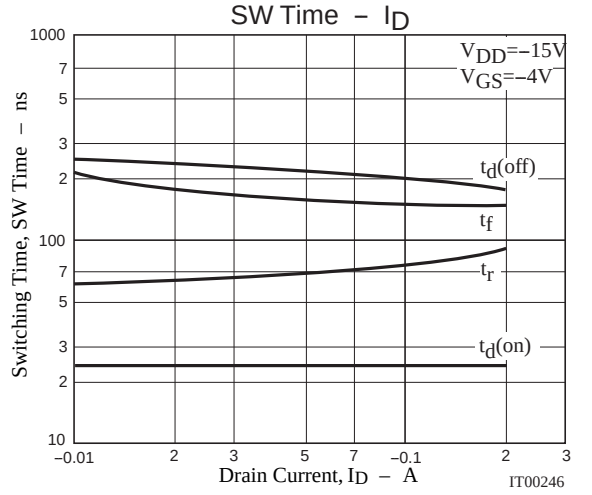
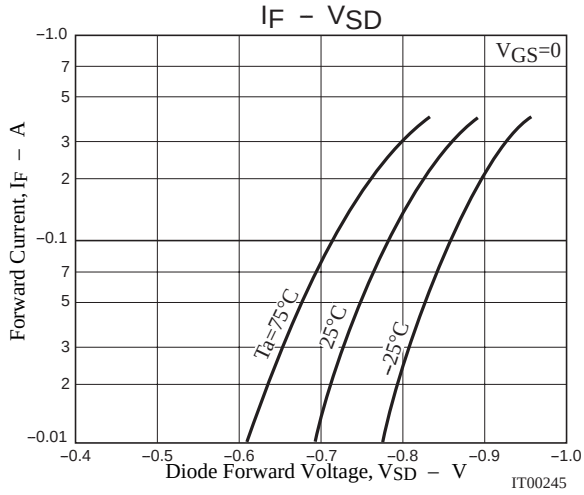
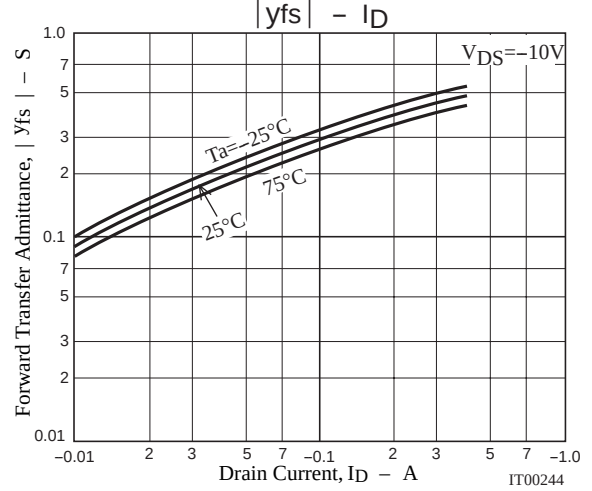
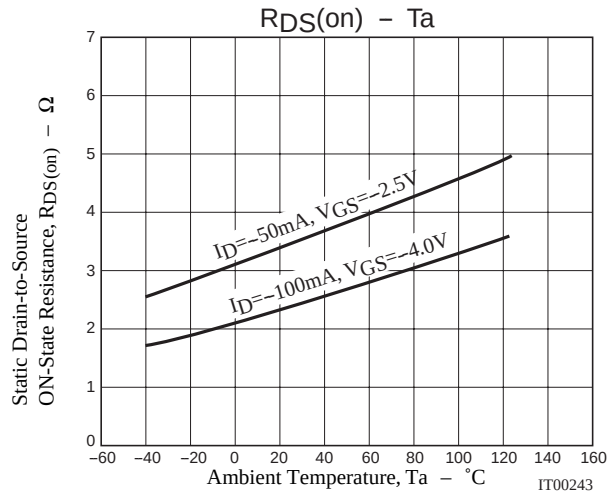
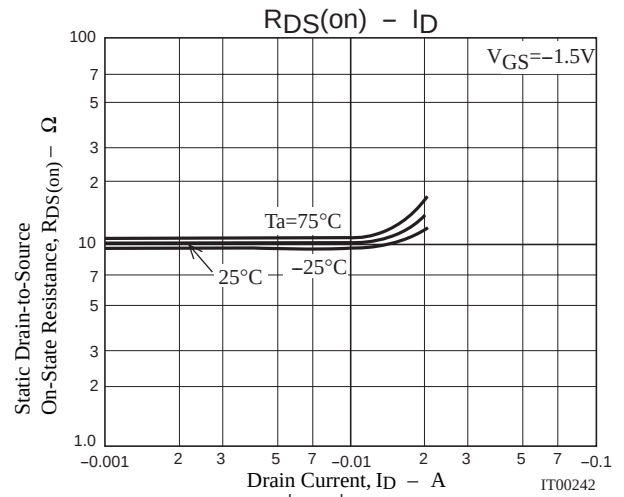
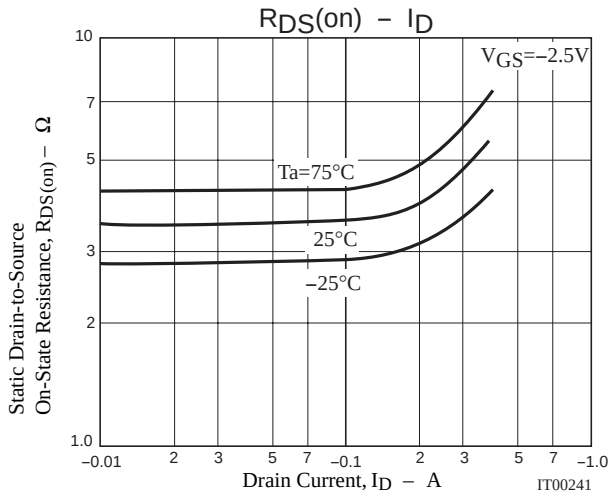
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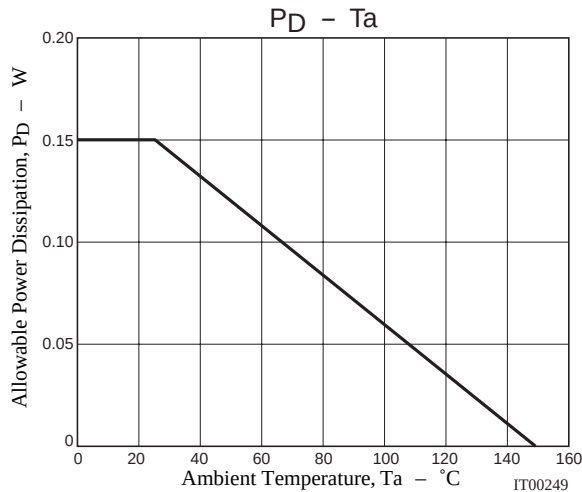
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	C_{iss}	$V_{DS} = -10V, f = 1MHz$		28		pF
Output Capacitance	C_{oss}	$V_{DS} = -10V, f = 1MHz$		15		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = -10V, f = 1MHz$		5.2		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		24		ns
Rise Time	t_r	See specified Test Circuit		75		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		200		ns
Fall Time	t_f	See specified Test Circuit		150		ns
Total Gate Charge	Q_g	$V_{DS} = -10V, V_{GS} = -10V, I_D = -200mA$		2		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS} = -10V, V_{GS} = -10V, I_D = -200mA$		0.25		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS} = -10V, V_{GS} = -10V, I_D = -200mA$		0.35		nC
Diode Forward Voltage	V_{SD}	$I_S = -200mA, V_{GS} = 0$		-0.82	-1.2	V

Switching Time Test Circuit



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